

MULTI-CHIP PACKAGE COMBINING WIRE-BONDING AND FLIP-CHIP

CONFIGURATION

FIELD OF THE INVENTION

The present invention relates to a multi-chip package (MCP), and more particularly to a multi-chip package combining wire-bonding and flip-chip configuration.

BACKGROUND OF THE INVENTION

Based on the more request of the semiconductor package, a multi-chip package is developed for assembling a plurality of chips which having the same or different functions to make a system in package (SIP). According the different types of the chips, the multi-chip package assembles several kinds of chips by wire-bonding and flip-chip connection.

R.O.C. Taiwan Patent No. 466719 entitled "multi chip module packaging method by mixing chip and package" disclosed a multi-chip module package. An encapsulating material on a substrate seals a wire-bonding chip and a chip scale package. The chip scale package is flip-chip mounted on the substrate, which includes a chip and a sub-package body. After mounting the chip scale package and the wire-bonding chip on the substrate, the encapsulating material seals the chip scale package and the wire-bonding chip by molding. To seal the chip scale package the substrate should have a larger dimension. In addition, the chip scale package is sealed inside the encapsulating material, so the chip scale package cannot be reworked after molding. When the functions test result of the multi-chip module package is NG, the whole package has to be scrapped. If the chip scale package is designed outside the encapsulating material, the plurality of contact pads on the substrate for electrically connecting the chip scale package are easily damaged by a molding tool for molding the encapsulating material, especially there is pre-solder printed on the contact pads. It would easily cause the substrate warpage.

SUMMARY OF THE INVENTION

1 A primary object of the present invention is to provide a multi-chip package
2 combining wire-bonding and flip-chip configuration. A molding compound with a
3 recession is formed on a substrate by a molding tool with an arc recession to seal chip(s)
4 with wire-bonding connection. The recession of the molding compound does not cover
5 a plurality of contact pads of the substrate for connecting with a flip-chip type electrical
6 device. The molding tool with the arc recession avoids damaging the contact pads
7 during molding process. And the substrate has a smaller dimension to configure the
8 chip(s) with wire-bonding connection and the flip-chip type electrical devices.

9 A second object of the present invention is to provide a multi-chip package
10 combining wire-bonding and flip-chip configuration. A molding compound with a
11 recession seals at least a wire-bonding chip on an upper surface of a substrate and
12 exposes the partial upper surface. At least a flip-chip type electrical device is mounted
13 on the exposed upper surface to provide a high-density multi-chip package combining
14 wire-bonding and flip-chip configuration. The molding compound has a plurality of
15 symmetric extensions from the recession to reduce substrate warpage.

16 According to the multi-chip package combining wire-bonding and flip-chip
17 configuration of the present invention, the package comprises a substrate, at least a
18 wire-bonding chip, a molding compound and at least a flip-chip type electrical device.
19 The substrate has an upper surface, a lower surface and a plurality of contact pads formed
20 on a flip chip region of the upper surface. The wire-bonding chip is attached to the
21 upper surface and electrically connected to the substrate by bonding wires. The molding
22 compound is formed on the partial upper surface for sealing the wire-bonding chip but
23 exposes the contact pads reserved for flip chip electrical devices. The molding
24 compound has at least a recession. Preferably, the recession is in a shape of an arc in
25 order to keep a distance from the nearest contact pads for clamping the molding tool.
26 Perfectly, the distance is over 1.0mm to avoid damaging the contact pads during molding
27 process. And the flip-chip type electrical device is connected to the contact pads of the

1 substrate to form the multi-chip package combining wire-bonding and flip-chip
2 configuration efficiently.

3 DESCRIPTION OF THE DRAWINGS

4 Fig.1 is a top view illustrating a multi-chip package combining wire-bonding and
5 flip-chip configuration according to a first embodiment of the present invention.

6 Fig.2 is a cross-section view illustrating the multi-chip package including
7 wire-bonding chip before mounting a flip-chip type electrical device according to the first
8 embodiment of the present invention.

9 Fig.3 is a cross-section view illustrating the multi-chip package combining
10 wire-bonding and flip-chip configuration across 3-3 line of Fig.1 according to the first
11 embodiment of the present invention.

12 Fig.4 is a schematic top plane view of a multi-chip package combining wire-bonding
13 and flip-chip configuration according to a second embodiment of the present invention.

14 Fig.5 is a schematic top plane view of a multi-chip package combining wire-bonding
15 and flip-chip configuration according to a third embodiment of the present invention.

16 Fig.6 is a schematic 3-D view of the multi-chip package combining wire-bonding
17 and flip-chip configuration according to the third embodiment of the present invention.

18 Fig.7 is a schematic 3-D view of a multi-chip package combining wire-bonding and
19 flip-chip configuration according to a forth embodiment of the present invention.

20 DETAIL DESCRIPTION OF THE INVENTION

21 Referring to the attached drawings, the present invention will be described by means
22 of the embodiments below.

23 According to a first embodiment of the present invention, a multi-chip package 100
24 combining wire-bonding and flip-chip configuration is showed in Fig.1, 2 and 3. Fig.1
25 is a top view illustrating the multi-chip package 100. Fig.2 is a cross-section view
26 illustrating the multi-chip package 100 before mounting a flip-chip type electrical device
27 140. Fig.3 is a cross-section view illustrating the multi-chip package 100 across 3-3 line

1 of Fig.1. The multi-chip package 100 comprises a substrate 110, at least a wire-bonding
2 chip 120, a molding compound 130 and at least a flip-chip type electrical device 140.

3 Referring to Fig.1 and 3, the substrate 110, such as multi-layer printed circuit board
4 or multi-layer ceramic substrate, has an upper surface 111 and a lower surface 112. A
5 plurality of contact pads 113 are formed on the upper surface 111, and wiring traces
6 electrically connect the upper surface 111 and the lower surface 112 (not show in the
7 drawings). At least a wire-bonding chip 120 is attached to the upper surface 111 of the
8 substrate 110 and is sealed by the molding compound 130. In this embodiment, there
9 are wire-bonding chips 120, 170 and 180 are sealed by the molding compound 130 on the
10 upper surface 111 of the substrate 110, so the molding compound 130 can be designed for
11 sealing a single or multiple chips.

12 The wire-bonding chip 120 means all kinds of integrated circuit chip electrically
13 connected by wire bonding. Referring to Fig.3, the wire-bonding chip 120 has an active
14 surface 121 and a back surface 122. The back surface 122 of the wire-bonding chip 120
15 is attached to the upper surface 111 of the substrate 110. A plurality of peripheral
16 bonding pads are formed on the active surface 121 (not show in the drawings), which are
17 electrically connected to the substrate 110 via a plurality of bonding wires 123. The
18 molding compound 130 seals the wire-bonding chip 120 and the bonding wires 123.

19 The molding compound 130 is selectively molded on the upper surface 111 of the
20 substrate 110 so as to partially cover the upper surface 111 of the substrate 110 for sealing
21 the wire-bonding chip 120, 170 and 180, but expose a flip chip region of the upper
22 surface 111 for mounting the flip-chip type electrical device 140. The molding
23 compound 130 is formed from a molding cavity of a molding tool through a molding gate
24 metal layer 114 on the upper surface 111 of the substrate 110 by a conventional molding
25 technology. And the molding tool is designed with an arc recession in order to form the
26 molding compound 130 having at least a recession 131. The molding gate metal layer
27 114 extends from periphery of the substrate 110 to the molding region opposing to the

1 recession 131. Preferably, the recession 131 is in a shape of an arc. The molding
2 compound 130 exposes the contact pads 113 of the substrate 110 because of the recession
3 131. Since the distance between the arc recession 131 of the molding compound 130
4 and the nearest contact pads 113a is more than 1.0mm, which 1.6mm is better, the
5 clamping area of the molding tool along the arc recession 131 will not contact the contact
6 pads 113 on the upper surface 111 of the substrate 110 during molding process. More
7 preferably, the recession 131 is in a shape of a quarter-circle to keep the distance
8 constant.

9 Referring to Fig.2, the molding compound 130 is formed prior to mounting the
10 flip-chip type electrical device 140. When molding the molding compound 130, the
11 contact pads 113 has a pre-solder 115 formed on them in order to mount the flip-chip type
12 electrical device 140 in flip chip mounting process. The pre-solder 115 is slightly
13 protruded from the upper surface 111 of the substrate 110. Because of the recession 131,
14 a molding tool for forming the molding compound 130 will not contact the contact pads
15 113 or pre-solder 115 so that the contact pads 113 will not be damaged. The molding
16 compound 130 has a plurality of symmetric extensions 132 from the recession 131 to
17 improve the warpage of the substrate 110. In this embodiment, the molding compound
18 130 is L-shape and partially covers the upper surface 111 of the substrate 110 except the
19 flip chip region (as show in Fig.1). In addition, the flip-chip type electrical device 140
20 is mounted on the exposed upper surface 111 (the flip chip region) of the substrate 110
21 that is not covered by the molding compound 130. The flip-chip type electrical device
22 140 includes at least a kind of integrated circuit chip in flip chip type, such as a flip chip
23 with array bumps, a chip scale package (CSP), a wafer level chip scale package (WLCSP)
24 or BGA package. In the embodiment, the flip-chip type electrical device 140 is a flip
25 chip that is mounted on the exposed upper surface 111 of the substrate 110. The flip
26 chip (i.e. flip-chip type electrical device 140) has an active surface 141. A plurality of
27 electric bumps 142 are formed on the active surface 141, and connect the contact pads

1 113 of the substrate 110. The wire-bonding chip 120 inside the molding compound 130
2 and the flip-chip type device 140 are combined on the upper surface 111 of the substrate
3 110. Preferably, an underfilling material 143 is filled between the flip-chip type
4 electrical device 140 and the substrate 110 to seal the bumps 142. Referring to Fig.3, a
5 heat sink 160 may be placed on the upper surface 111 of the substrate 110. The heat
6 sink 160 is attached to the molding compound 130 and the flip-chip type electrical device
7 140 to improve the heat dissipation of the multi-chip package 100 and to reduce the
8 warpage of the substrate 110. After configuring the wire-bonding chips 120, 170, 180
9 and flip-chip type electrical device 140, a plurality of solder balls 150 are placed on the
10 lower surface 112 of the substrate 110 which electrically connect the wire-bonding chips
11 120, 170, 180 and flip-chip type electrical device 140 respectively to become a multi-
12 chip ball grid array package.

13 So, the multi-chip package 100 of the present invention has the capability of
14 configuring both the wire-bonding and flip-chip type in a multi-chip package, moreover,
15 the molding compound 130 will not damage the contact pads 113 during the molding
16 process. Because that the molding compound 130 has a recession 131 not to seal the
17 flip-chip type electrical device 140, therefore, the substrate 100 does not need to increase
18 substrate dimension to accommodate underfilling material(s) 143 for the flip-chip type
19 electrical device 140. The dimension of the substrate 110 can be reduced to form a
20 smaller multi-chip package combining wire-bonding and flip-chip configuration,
21 meanwhile, the consumption of the molding compound 130 can also be reduced.

22 Referring to Fig.4, another multi-chip package 200 combining wire-bonding and
23 flip-chip configuration is disclosed according to a second embodiment of the present
24 invention. The multi-chip package 200 comprises a substrate 210, a molding compound
25 220 and a flip-chip type electrical device 230. An upper surface 222 of the substrate
26 210 has a plurality of contact pads 212. The molding compound 220 formed by
27 molding process seals at least an integrated circuit chip electrically connecting by wire

1 bonding (not show in the drawing). The molding compound 220 partially covers the
2 upper surface 211 of the substrate 210 but not covers the contact pads 212. In this
3 embodiment, the molding compound 220 has a first recession 221, a second recession
4 222 and two symmetric extensions from the recession 221,222. The molding compound
5 220 is in a U-shape to expose the contact pads 212 on the substrate 210. The recession
6 221, 222 are in a shape of an arc to keep a suitable distance from each recession 221, 222
7 to the contact pads 212 is kept around 1.0~ 3.0 mm, so the contact pads 212 and the
8 pre-solder thereon (not show in the drawing) will not be damaged by a molding tool
9 during molding process. The flip-chip type electrical device 230 is mounted on the
10 exposed region of the upper surface 211, which is not covered by the molding compound
11 220, and is electrically connected to the contact pads 212. Therefore it is possible to
12 rework the flip-chip type electrical device 230 after flip chip mounting process. The
13 multi-chip package 200 can be configured both the wire-bonding and flip-chip type chips
14 without damaging the contact pads 212 during the molding process and improve the yield
15 of assembly MCP's.

16 Furthermore, the molding compound has many kinds of equivalent variations. A
17 third and a forth embodiments according to the present invention are illustrated for easily
18 understanding. Referring to Fig.5 and 6, a multi-chip package 300 is disclosed
19 according to the third embodiment of the present invention. The multi-chip package
20 300 comprises a substrate 310 having a plurality of contact pads 312 and 312a, a flip-chip
21 type electrical device 320 and a molding compound 330. The molding compound 330 is
22 selectively formed on the upper surface 311 of the substrate 310 and seals at least a
23 semiconductor chip (not show in the drawing), without covering the contact pads 312 and
24 312a formed on the partially exposed upper surface 311. The molding compound 330
25 has a recession 331 in a shape of an arc to keep the recession 331 a suitable distance from
26 the nearest contact pads 312a which should be more than 1.0 mm, to avoid a molding tool
27 to damage the contact pad 312, 312a during the molding process. The molding

1 compound 330 forms a step 333 (as show in the Fig. 6) at connecting portion of the
2 symmetric extensions 332 (at two sides) to decrease the thickness of the symmetric
3 extensions 332 in order to reduce the warpage of the substrate 310. In the third
4 embodiment of the present invention, the flip-chip type electrical device 320 is a ball grid
5 array flip-chip package or a chip scale package. The flip-chip type electrical device 320
6 includes a flip chip 321 and a substrate 322. The flip chip 321 is mounted on the
7 substrate 322 using flip-chip configuration. On the lower surface of the substrate 321
8 there are a plurality of solder balls 323 which are connected with the contact pads 312
9 and 312a.

10 Referring to Fig. 7, another multi-chip package combining wire-bonding and
11 flip-chip configuration is disclosed according to the forth embodiment of the present
12 invention. The multi-chip package comprises some components, such as a substrate 310
13 with a plurality of contact pads, a molding compound 330 which seals wire-bonding
14 chips and a flip-chip type electrical device 320, which are the same as the third
15 embodiment of the present invention and use the same figure number. The molding
16 compound 330 is selectively formed on the upper surface 311 of the substrate 310 by
17 molding process. The molding compound 330 has a recession 331 and symmetric
18 extensions 332 from two sides of the recession 331. The molding compound 330 forms
19 an indentation 333 at the connecting portion of the symmetric extensions 332 to achieve
20 reducing the warpage of the substrate 310.

21 The above description of embodiments of this invention is intended to be illustrated
22 and not limiting. Other embodiments of this invention will be obvious to those skilled
23 in the art in view of the above disclosure.

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